



FEATURES

- Common cathode structure
- Low power loss, high efficiency
- High Operating Junction Temperature
- Guard ring for overvoltage protection, High reliability
- RoHS product

APPLICATIONS

- High frequency switch Power supply
- Free wheeling diodes, Polarity protection applications

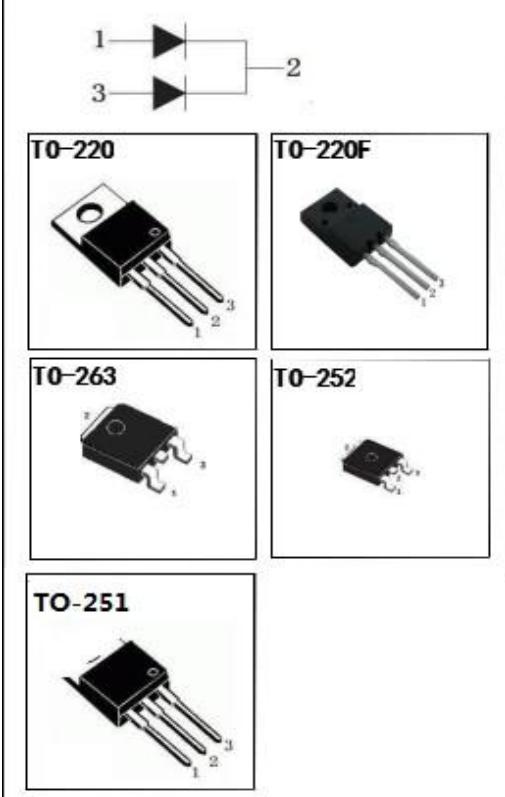
主要参数 MAIN CHARACTERISTICS

$I_{F(AV)}$	10 (2×5) A
$V_{F(max)}$	0.7V (@ $T_j=125^\circ\text{C}$)
T_j	175 °C
V_{RRM}	100 V

产品特性

- 共阴结构
- 低功耗，高效率
- 良好的高温特性
- 有过压保护环，高可靠性
- 环保（RoHS）产品

封装



用途

- 高频开关电源
- 低压续流电路和保护电路

产品型号信息 PRODUCT MESSAGE

型号 Model	印记 Marking	封装 Package
MBR10100C	MBR10100C	TO-220
MBRF10100	MBRF10100	TO-220F
MBR10100S	MBR10100S	TO-263
MBR10100R	MBR10100R	TO-252
MBR10100V	MBR10100V	TO-251



MBR10100 肖特基二极管 SCHOTTKY DIODE

绝对最大额定值 ABSOLUTE RATINGS ($T_c=25^\circ\text{C}$)

项 目 Parameter	符 号 Symbol	数 值 Value	单 位 Unit
最大反向重复峰值电压 Repetitive peak reverse voltage	V_{RRM}	100	V
最大直流阻断电压 Maximum DC blocking voltage	V_{DC}	100	V
正向平均整流电流 Average forward current	$I_{F(AV)}$	10 5	A
($T_c=150^\circ\text{C}$ (TO-220/263/252) $T_c=125^\circ\text{C}$ (TO-220F))	整个器件 per device 单 侧 per diode		
正向峰值浪涌电流 Surge non repetitive forward current (额定负载 8.3ms 半正弦波—按 JEDEC 方法) 8.3 ms single half-sine-wave (JEDEC Method)	I_{FSM}	85	A
最高结温 Maximum junction temperature	T_j	175	$^\circ\text{C}$
储存温度 Storage temperature range	T_{STG}	-40~+150	$^\circ\text{C}$

电特性 ELECTRICAL CHARACTERISTICS

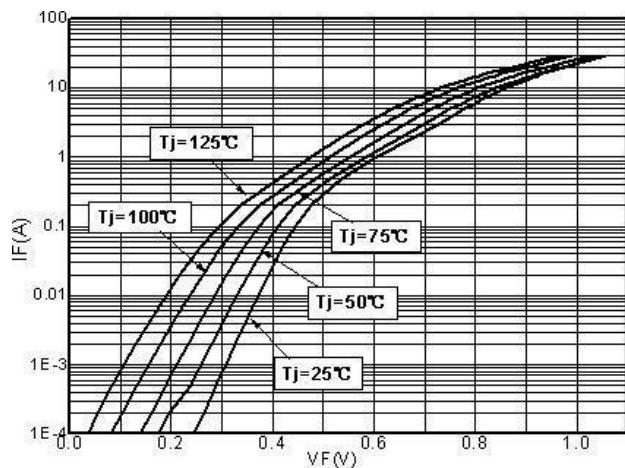
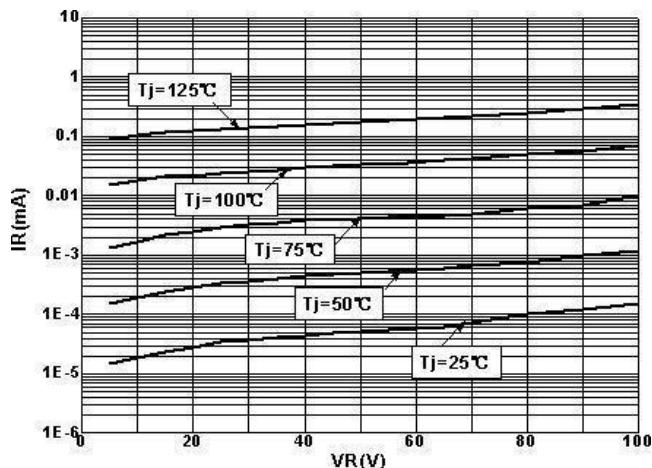
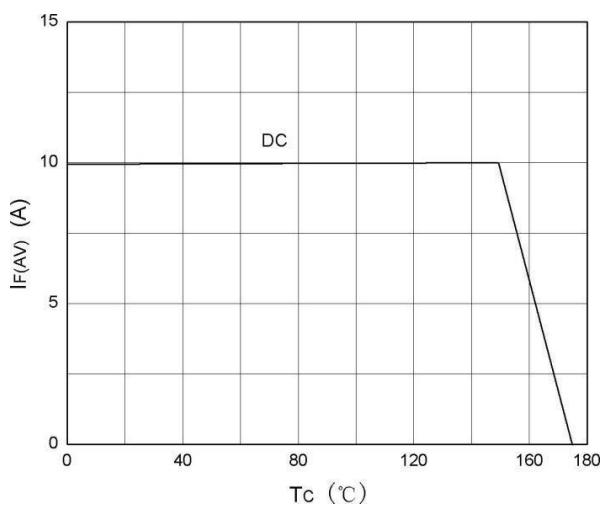
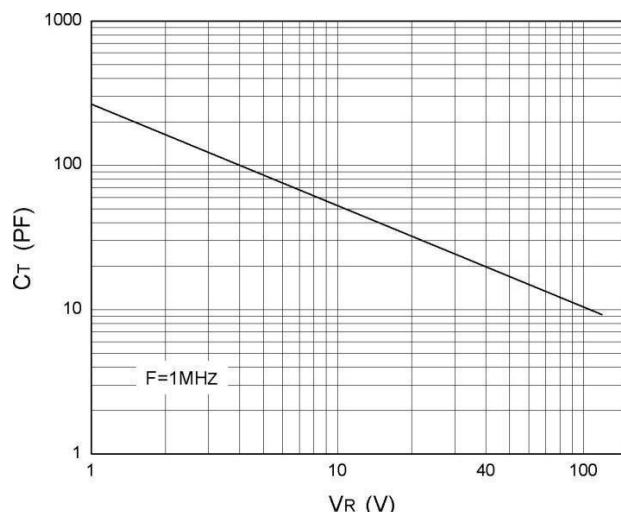
项 目 Parameter	测试条件 Tests conditions		最 小 值 Value(min)	典 型 值 Value(typ)	最 大 值 Value(max)	单 位 Unit
I_R	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			10	μA
	$T_j = 125^\circ\text{C}$				5	mA
V_F	$T_j = 25^\circ\text{C}$	$I_F = 5\text{A}$		0.77	0.83	V
	$T_j = 125^\circ\text{C}$			0.64	0.7	V
	$T_j = 25^\circ\text{C}$	$I_F = 10\text{A}$		0.86	0.9	V
	$T_j = 125^\circ\text{C}$			0.73	0.8	V

热特性 THERMAL CHARACTERISTICS

项 目 Parameter	符 号 Symbol	最 小 值 Value(min)	最 大 值 Value(max)	单 位 Unit
结到管壳的热阻 Thermal resistance from junction to case	$R_{th(j-c)}$		1.9 3.5 1.9 3	$^\circ\text{C/W}$
TO-220			1.9	
TO-220F			3.5	
TO-263			1.9	
TO-252			3	



特征曲线 ELECTRICAL CHARACTERISTICS (curves)

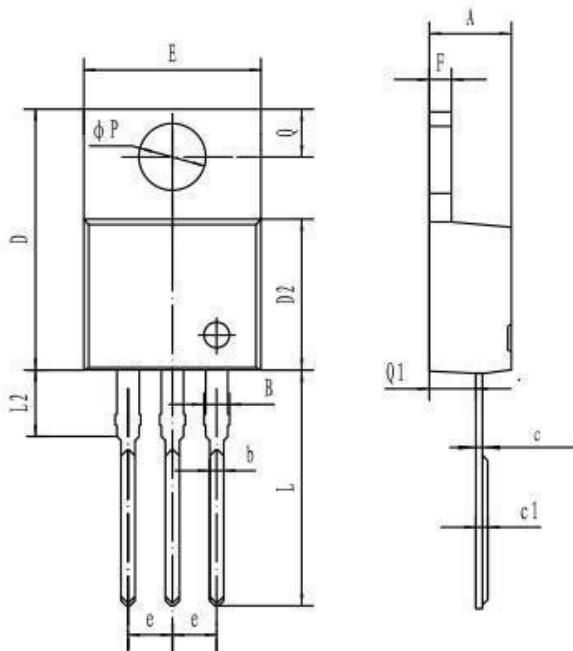
I_F vs V_FI_R vs V_RI_{F(AV)} vs T_CC_T vs V_R



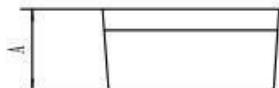
MBR10100 肖特基二极管 SCHOTTKY DIODE

外形尺寸 PACKAGE MECHANICAL DATA
TO-220

单位 Unit : mm

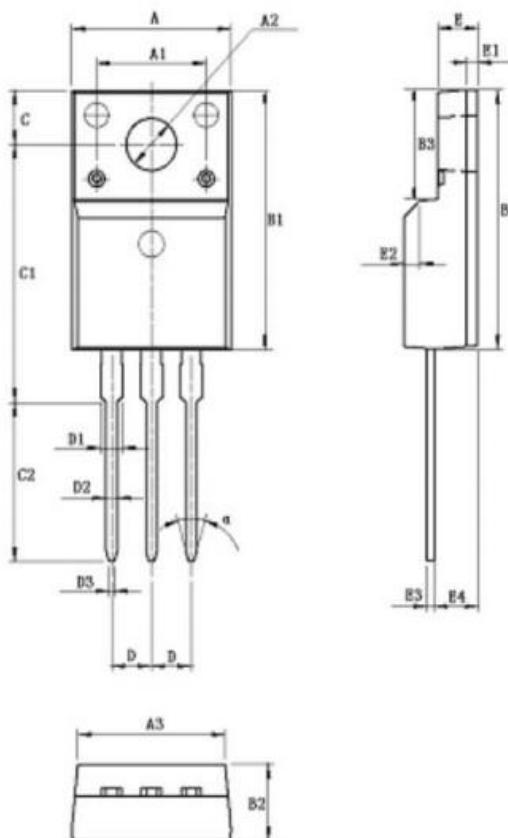


符号 symbol	MIN	MAX
A	4.40	4.80
B	1.10	1.40
b	0.70	0.95
c	0.28	0.48
c1	0.32	0.52
D	14.45	16.00
D2	8.20	9.20
E	9.60	10.40
e	2.39	2.69
F	1.20	1.35
L	13.05	14.05
L2	3.70	3.90
Q	2.40	3.00
Q1	2.20	2.90
P	3.50	4.00



Package Dimension

TO-220F



单位: mm

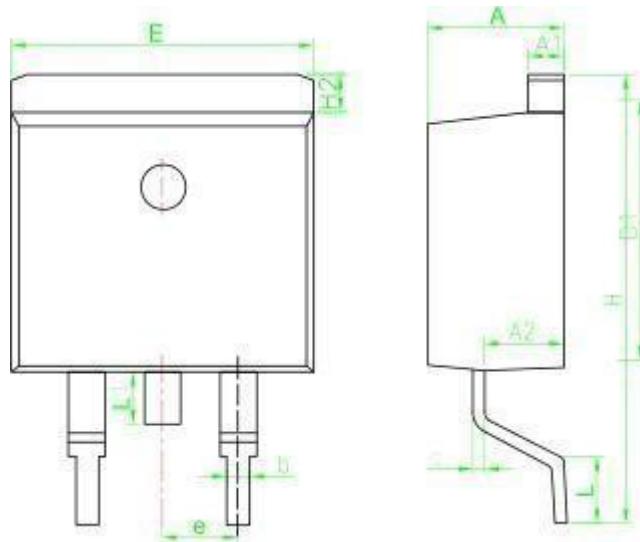
Symbol	Min	Max	Symbol	Min	Max
A	9.96	10.36	D		2.54
A1		7.00	D1	1.15	1.35
A2	3.08	3.28	D2	0.70	0.90
A3	9.25	9.65	D3	0.28	0.48
B1	15.70	16.10	E	2.34	2.74
B2	4.50	4.90	E1		0.70
B3	6.20	6.80	E2		1.0×45°
C	3.20	3.40	E3	0.36	0.65
C1	15.20	16.00	E4	2.55	2.95
C2	9.75	10.15	a(度)		30°



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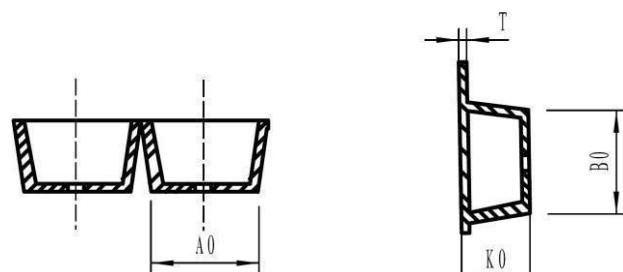
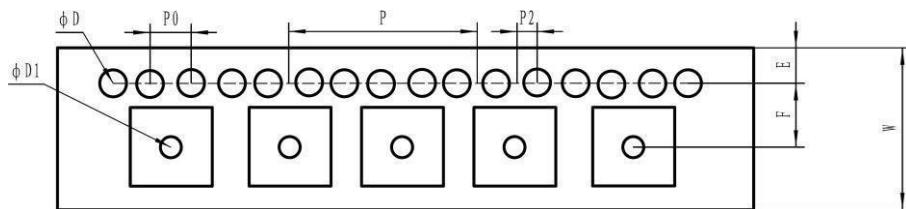
外形尺寸 PACKAGE MECHANICAL DATA
TO-263

单位 Unit : mm



SYMBOL	MM	
	MIN	MAX
A	4.30	4.80
A1	1.12	1.42
A2	2.54	2.84
b	0.67	1.00
c	0.29	0.52
D1	8.40	9.00
E	9.80	10.46
e	2.54BSC	
H	14.00	16.00
H2	1.12	1.45
L	1.50	3.10
L1	1.45	1.70

编 带 REEL



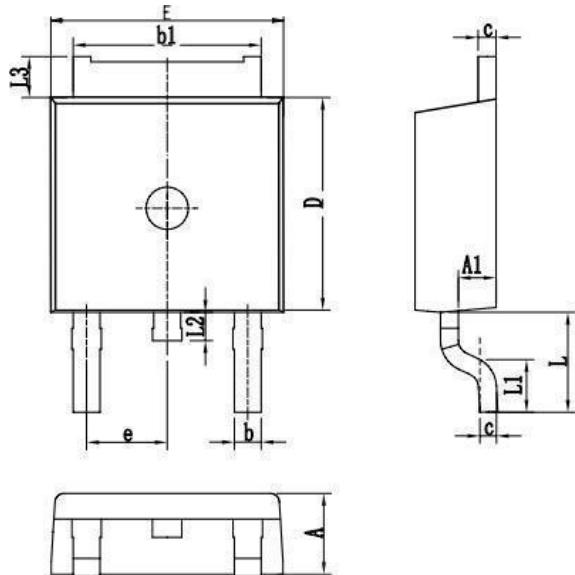
产品尺寸规格 (UNIT:mm)				
规格	W	A0	E	F
尺寸	24 ± 0.3	10.9 ± 0.2	1.75 ± 0.2	11.5 ± 0.2
规格	D1	P0	P2	P
尺寸	1.5 +0.2/-0.1	4 ± 0.2	2 ± 0.2	16 ± 0.2
规格	K0	B0		
尺寸	4.9 ± 0.2	16.0 ± 0.2		



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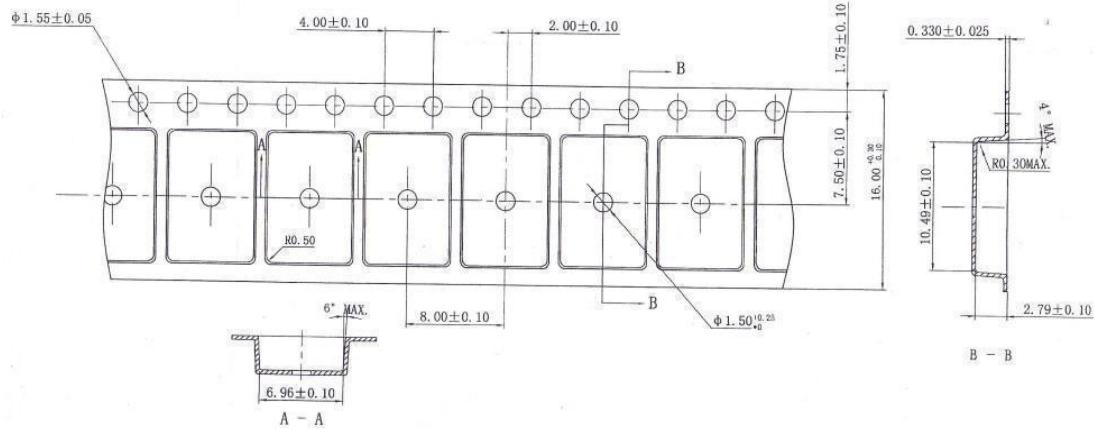
外形尺寸 PACKAGE MECHANICAL DATA
TO-252

单位 Unit : mm



SYMBOL	mm	
	MIN	MAX
A	2.10	2.50
A1	0.80	1.20
b	0.66	0.96
b1	5.10	5.50
c	0.40	0.62
D	5.85	6.45
E	6.30	6.90
e	2.286BSC	
L	2.40	3.00
L1	0.85	1.45
L2	0.60	1.10
L3	0.67	1.07

编带 REEL

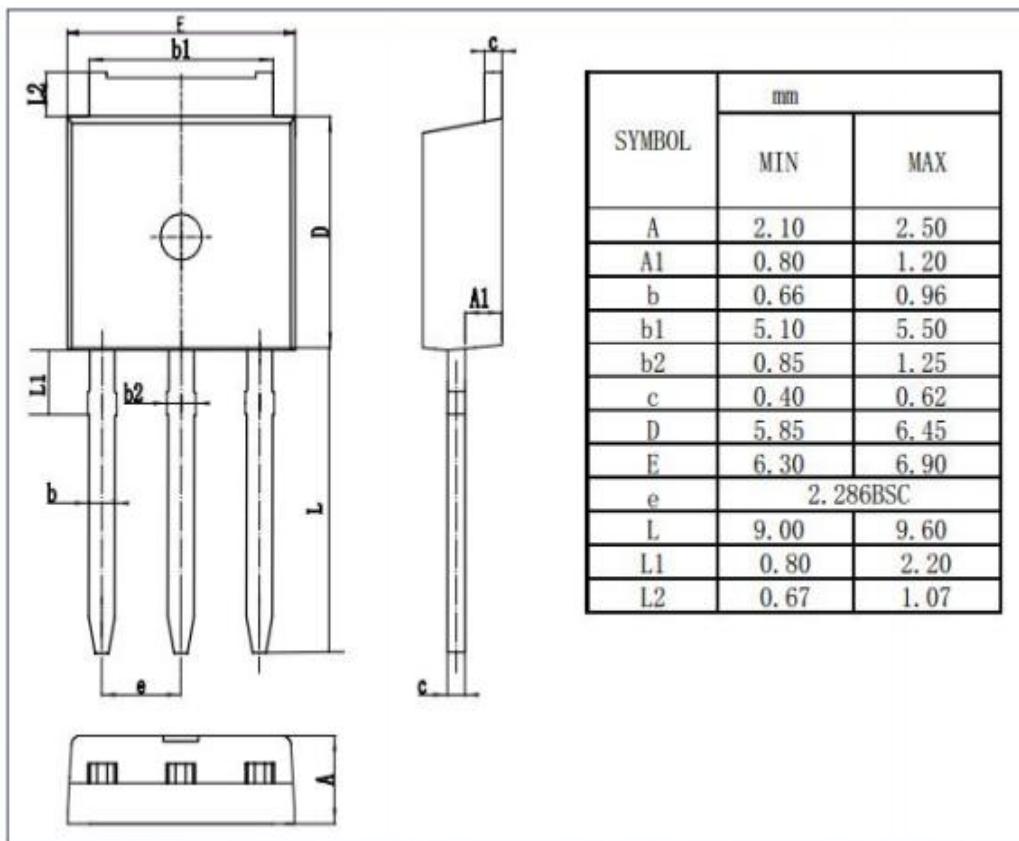




MBR10100 肖特基二极管 SCHOTTKY DIODE

外形尺寸 PACKAGE MECHANICAL DATA
TO-251

单位 Unit : mm



**注意事项**

1. 深圳市华天微电子有限公司的产品销售分为直销和销售代理，无论哪种方式，订货时请与公司核实。
2. 购买时请认清公司商标，如有疑问请与公司本部联系。
3. 在电路设计时请不要超过器件的绝对最大额定值，否则会影响整机的可靠性。
4. 本说明书如有版本变更不另外告知

NOTE

1. Shenzhen Huatianwei Electronics co., Ltd sales its product either through direct sales or sales agent , thus, for customers, when ordering , please check with our company.
2. We strongly recommend customers check carefully on the trademark when buying our product, if there is any question, please don't be hesitate to contact us.
3. Please do not exceed the absolute maximum ratings of the device when circuit designing.
4. Shenzhen Huatianwei Electronics co., Ltd reserves the right to make changes in this specification sheet and is subject to change without prior notice.

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